## NSN 5961-01-218-5523



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-218-5523 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.562 inches and 0.950 inches Overall Width: 1.050 inches **End Application:** Lamps mark 3, sh-60b **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 collector to base voltage/static/emitter open and 350.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 4.00 amperes source cutoff current and 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life:

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

N/a

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